

HVM16

Variable Capacitance Diode for FM tuner

HITACHI

Preliminary
Rev. 3
May. 1993

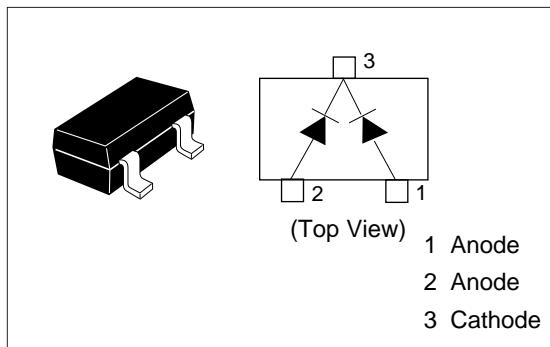
Features

- Worked by 8V, suitable for small manufacture sources of electric power.
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HVM16	T 3	MPAK

Pin Arrangement



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Reverse voltage	V_R	14	V
Power dissipation	P_d	150	mW
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse voltage	V_R	14.0	—	—	V	$I_R = 10 \mu\text{A}$
Reverse current	I_R	—	—	50.0	nA	$V_R = 9 \text{ V}$
Capacitance	C	43.0	—	48.1	pF	$V_R = 2 \text{ V}, f = 1 \text{ MHz}$
Capacitance ratio	$\frac{n_1}{n_2}$	1.23	—	1.33	—	C_2/C_4
Figure of merit	Q	75	—	—	—	$V_R = 2 \text{ V}, f = 100 \text{ MHz}$

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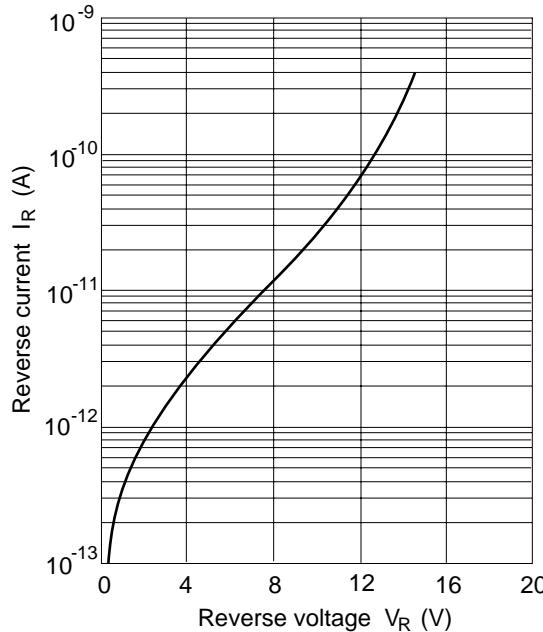


Fig.1 Reverse current Vs.
Reverse voltage

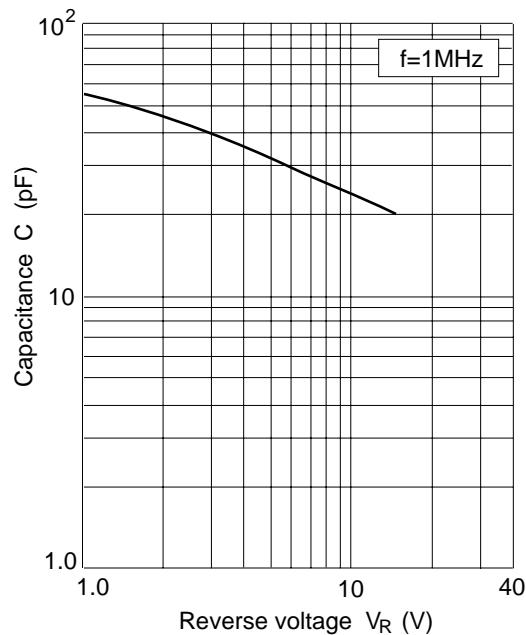


Fig.2 Capacitance Vs.
Reverse voltage

Package Dimensions

Unit: mm

